

MOS FIELD EFFECT TRANSISTOR

μ PA2719AGR

SWITCHING

P-CHANNEL POWER MOS FET

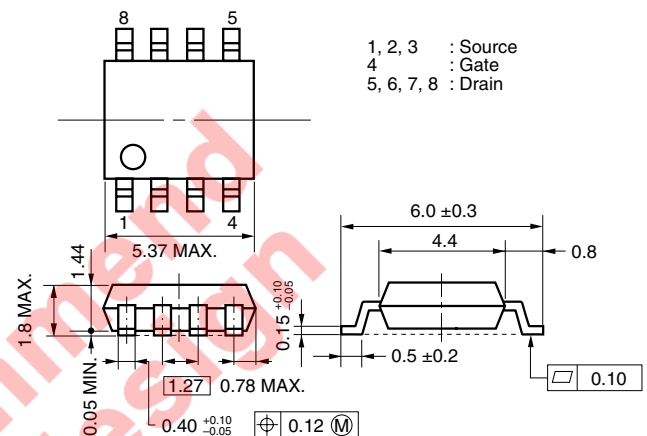
DESCRIPTION

The μ PA2719AGR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Lithium-Ion battery protection circuit.

FEATURES

- Low on-state resistance
 $R_{DS(on)1} = 13 \text{ m}\Omega \text{ MAX. (} V_{GS} = -10 \text{ V, } I_D = -5.0 \text{ A)}$
 $R_{DS(on)2} = 20.9 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -5.0 \text{ A)}$
- Low input capacitance
 $C_{iss} = 2010 \text{ pF TYP.}$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)

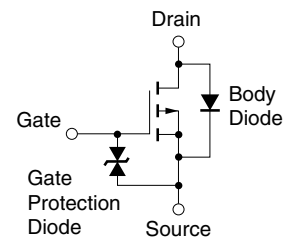
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, All terminals are connected.)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	-30	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC)	$I_{D(DC)}$	± 10	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	± 100	A
Total Power Dissipation ^{Note2}	P_{T1}	2	W
Total Power Dissipation ^{Note3}	P_{T2}	2	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Single Avalanche Current ^{Note4}	I_{AS}	-10	A
Single Avalanche Energy ^{Note4}	E_{AS}	10	mJ

EQUIVALENT CIRCUIT



Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Mounted on ceramic substrate of $1200 \text{ mm}^2 \times 2.2 \text{ mm}$
3. Mounted on glass epoxy board of $25.4 \text{ mm} \times 25.4 \text{ mm} \times 0.8 \text{ mm}$, $PW = 10 \text{ sec}$
4. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = -15 \text{ V}$, $R_G = 25 \Omega$, $L = 100 \mu\text{H}$, $V_{GS} = -20 \rightarrow 0 \text{ V}$

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

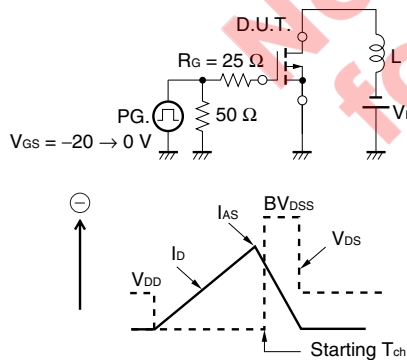
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ELECTRICAL CHARACTERISTICS (T_A = 25°C, All terminals are connected.)

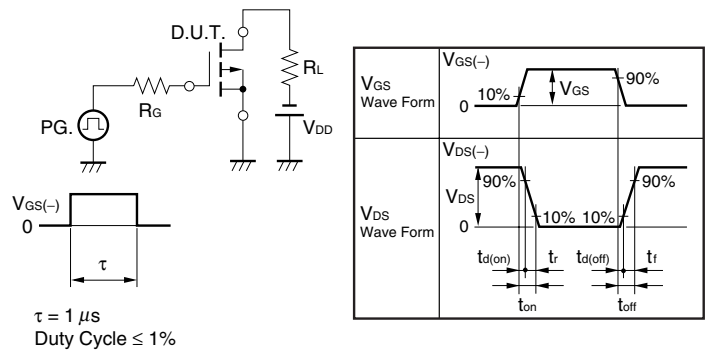
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V			-1	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.0		-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -5.0 A	8			S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = -10 V, I _D = -5.0 A		10.6	13	mΩ
	R _{DS(on)2}	V _{GS} = -4.5 V, I _D = -5.0 A		14.2	20.9	mΩ
	R _{DS(on)3}	V _{GS} = -4.0 V, I _D = -5.0 A		16.6	25.5	mΩ
Input Capacitance	C _{iss}	V _{DS} = -10 V		2010		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		460		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		350		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = -15 V, I _D = -5.0 A		12		ns
Rise Time	t _r	V _{GS} = -10 V		15		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		290		ns
Fall Time	t _f			180		ns
Total Gate Charge	Q _G	V _{DD} = -24 V		43		nC
Gate to Source Charge	Q _{GS}	V _{GS} = -10 V		5.5		nC
Gate to Drain Charge	Q _{GD}	I _D = -10 A		12		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 10 A, V _{GS} = 0 V		0.84		V
Reverse Recovery Time	t _{rr}	I _F = 10 A, V _{GS} = 0 V		105		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 50 A/μs		6.7		nC

Note Pulsed

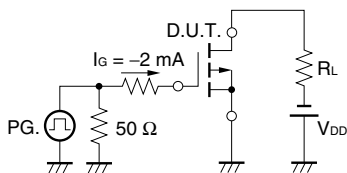
TEST CIRCUIT 1 AVALANCHE CAPABILITY



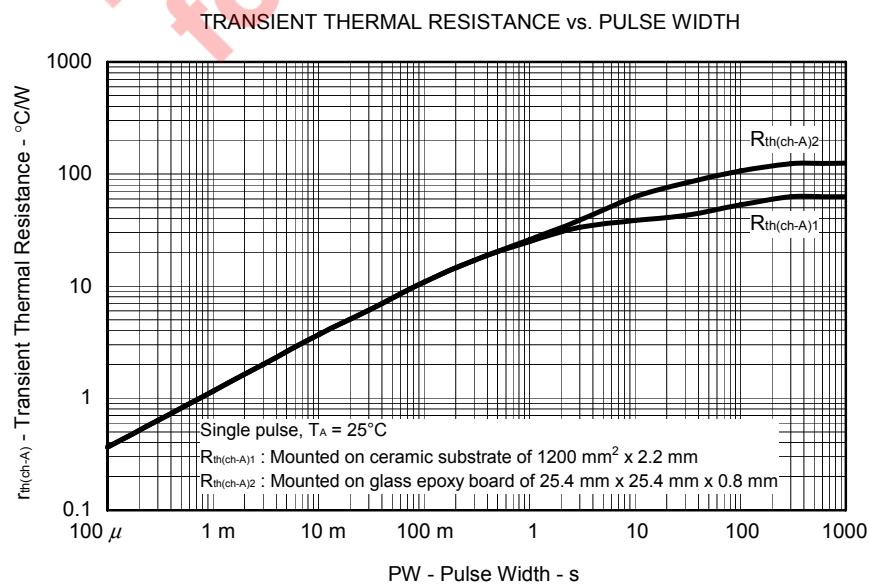
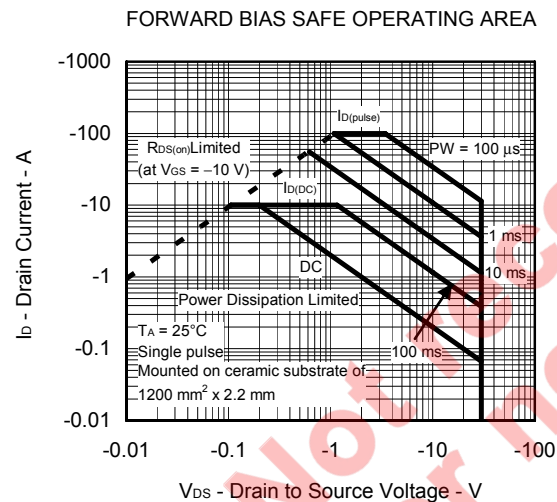
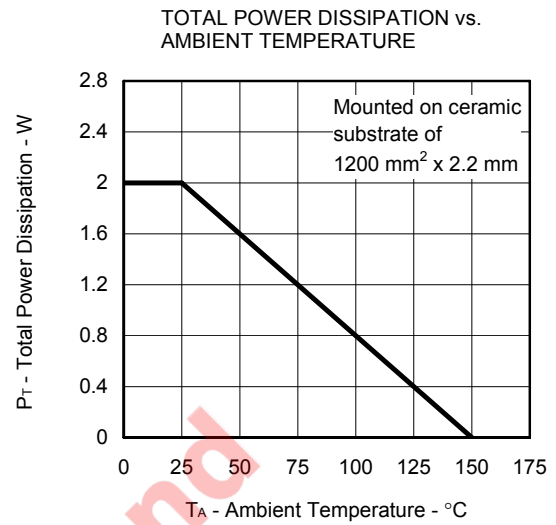
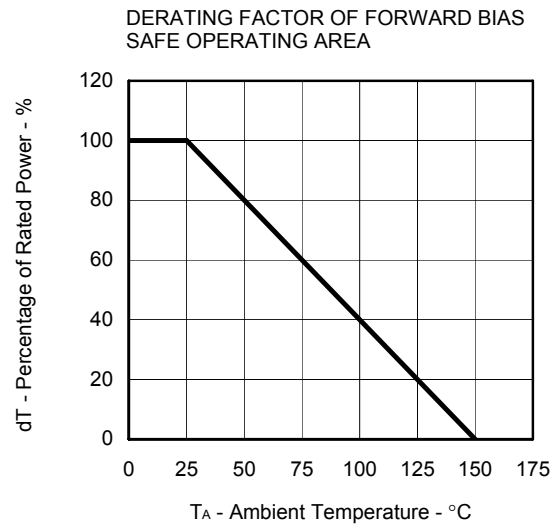
TEST CIRCUIT 2 SWITCHING TIME



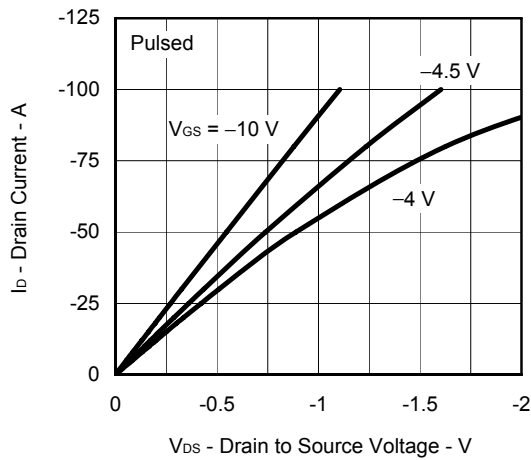
TEST CIRCUIT 3 GATE CHARGE



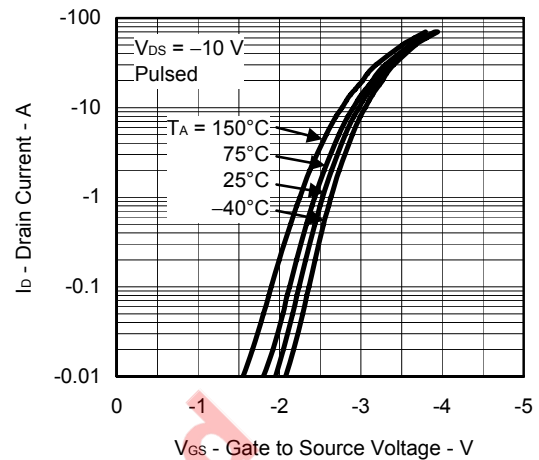
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



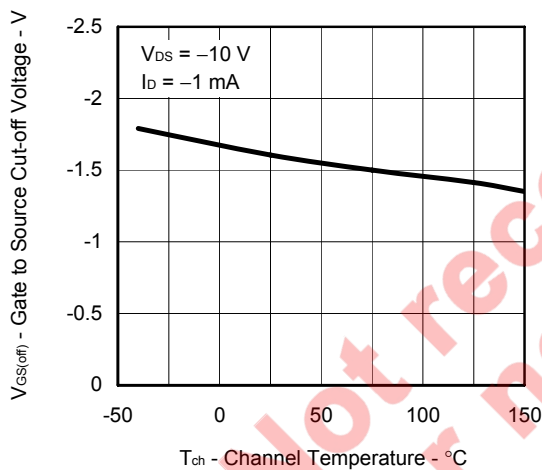
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



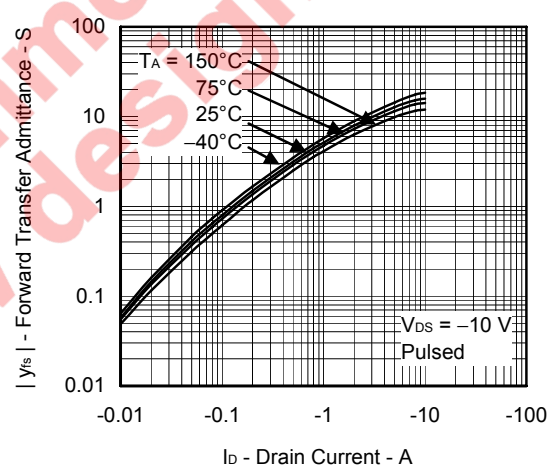
FORWARD TRANSFER CHARACTERISTICS



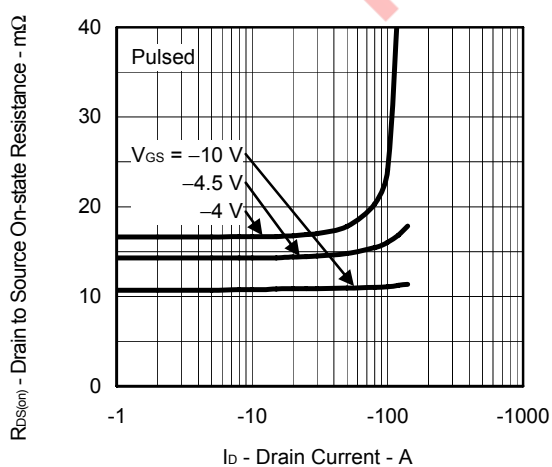
GATE TO SOURCE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



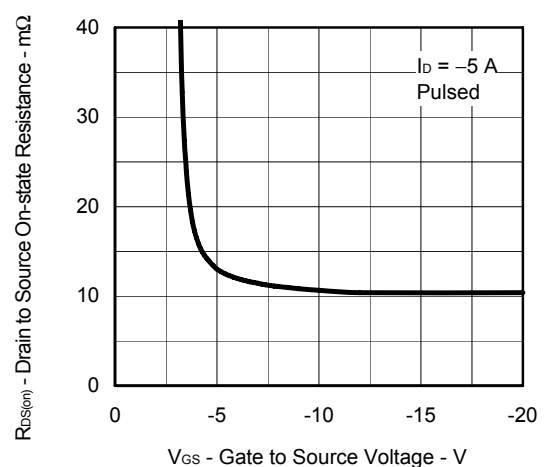
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



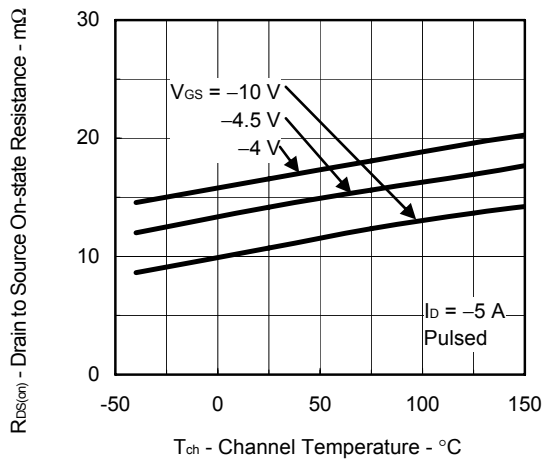
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



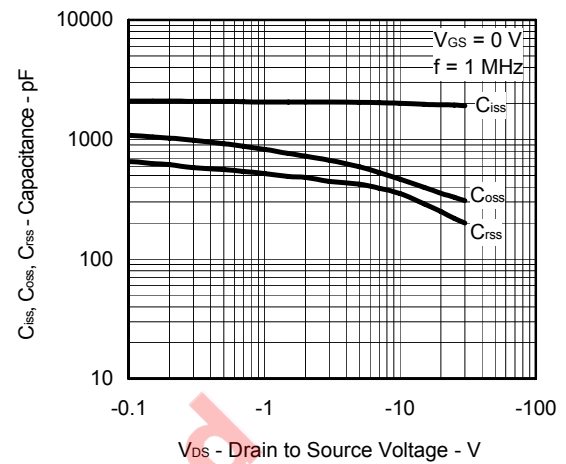
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



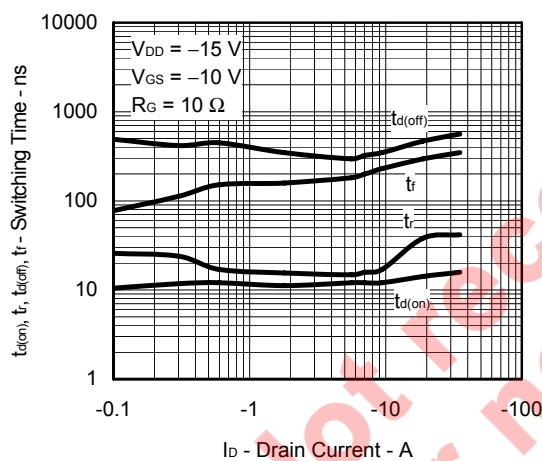
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



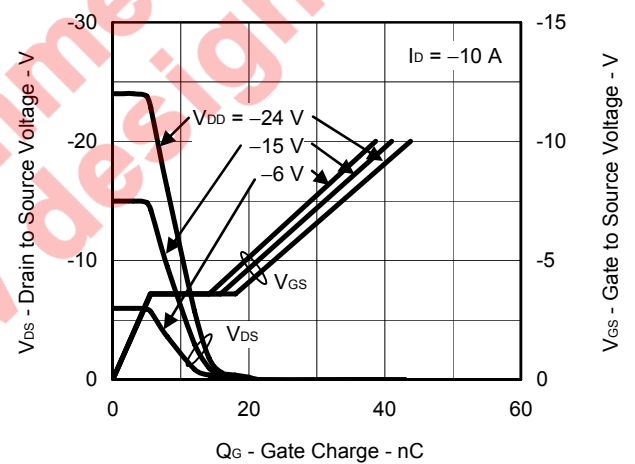
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



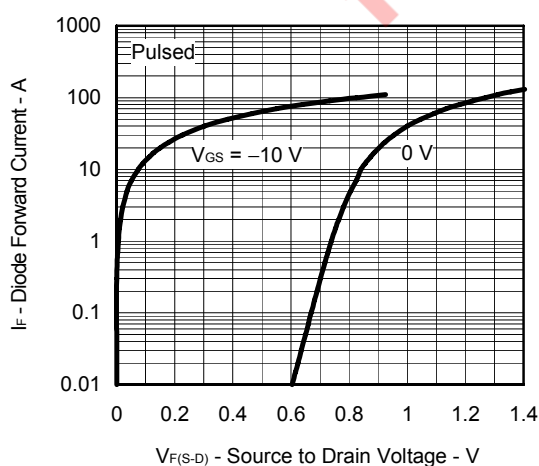
SWITCHING CHARACTERISTICS



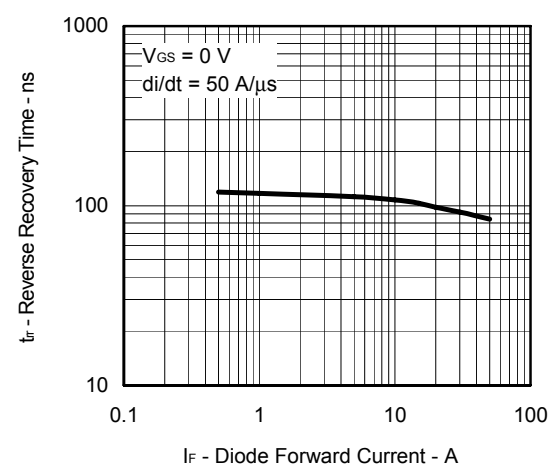
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

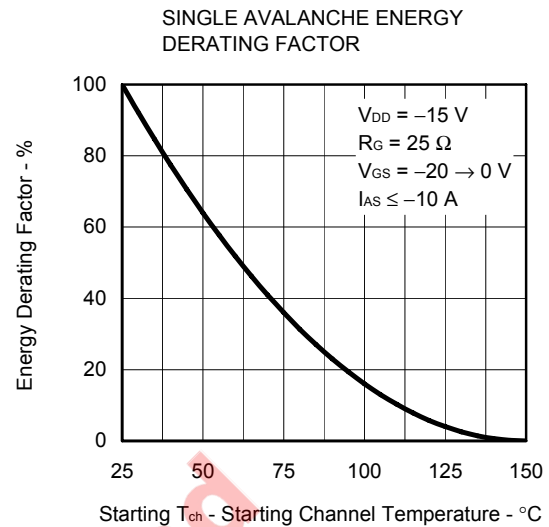
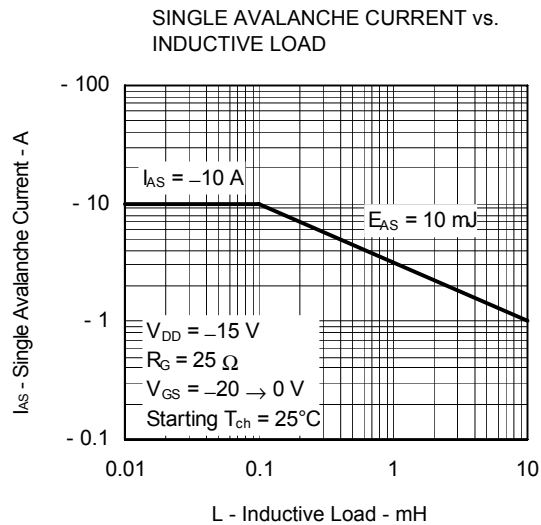


SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μ PA2719AGR-E1-AT ^{Note}	Pure Sn (Tin)	Tape 2500 p/reel	Power SOP8
μ PA2719AGR-E2-AT ^{Note}			0.08 g TYP.

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

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